Quad 2-input NAND gate 74HC00; 74HCT00

FEATURES

- Complies with JEDEC standard no. 8-1A
- ESD protection:
  HBM EIA/JESD22-A114-A exceeds 2000 V
  MM EIA/JESD22-A115-A exceeds 200 V
- Specified from –40 to +85 °C and –40 to +125 °C.

DESCRIPTION

The 74HC00/74HCT00 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A.

The 74HC00/74HCT00 provide the 2-input NAND function.

QUICK REFERENCE DATA

GND = 0 V; T_{amb} = 25 °C; $t_r = t_f$ = 6 ns.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			74HC00	74HCT00	
t_{PHL}/t_{PLH}	propagation delay nA, nB to nY	C_L = 15 pF; V_{CC} = 5 V	7	10	ns
C_I	input capacitance		3.5	3.5	pF
C_{PD}	power dissipation capacitance per gate	notes 1 and 2	22	22	pF

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
   $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:
   f_i = input frequency in MHz;
   f_o = output frequency in MHz;
   C_L = output load capacitance in pF;
   V_{CC} = supply voltage in Volts;
   N = total load switching outputs;
   $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.
2. For 74HC00 the condition is V_I = GND to V_{CC}.
   For 74HCT00 the condition is V_I = GND to V_{CC} – 1.5 V.

FUNCTION TABLE

See note 1.

INPUT		OUTPUT
nA	nB	nY
L	L	H
L	H	H
H	L	H
H	H	L

Note

1. H = HIGH voltage level;
   L = LOW voltage level.

ORDERING INFORMATION

TYPE NUMBER	PACKAGE				
	TEMPERATURE RANGE	PINS	PACKAGE	MATERIAL	CODE
74HC00N	–40 to +125 °C	14	DIP14	plastic	SOT27-1
74HCT00N	–40 to +125 °C	14	DIP14	plastic	SOT27-1
74HC00D	–40 to +125 °C	14	SO14	plastic	SOT108-1
74HCT00D	–40 to +125 °C	14	SO14	plastic	SOT108-1
74HC00DB	–40 to +125 °C	14	SSOP14	plastic	SOT337-1
74HCT00DB	–40 to +125 °C	14	SSOP14	plastic	SOT337-1
74HC00PW	–40 to +125 °C	14	TSSOP14	plastic	SOT402-1
74HCT00PW	–40 to +125 °C	14	TSSOP14	plastic	SOT402-1
74HC00BQ	–40 to +125 °C	14	DHVQFN14	plastic	SOT762-1
74HCT00BQ	–40 to +125 °C	14	DHVQFN14	plastic	SOT762-1

PINNING

PIN	SYMBOL	DESCRIPTION
1	1A	data input
2	1B	data input
3	1Y	data output
4	2A	data input
5	2B	data input
6	2Y	data output
7	GND	ground (0 V)
8	3Y	data output
9	3A	data input
10	3B	data input
11	4Y	data output
12	4A	data input
13	4B	data input
14	V_{CC}	supply voltage

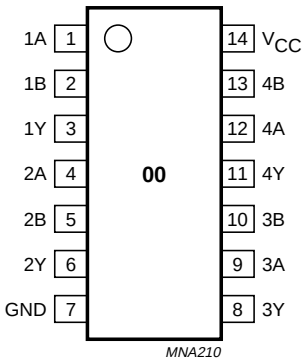
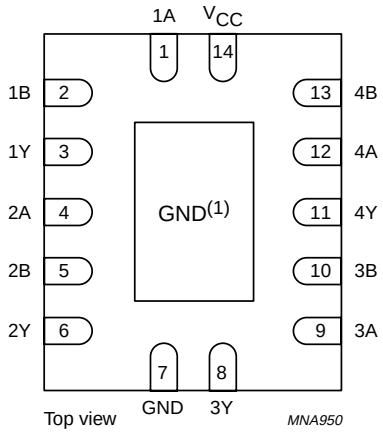


Fig.1 Pin configuration DIP14, SO14 and (T)SSOP14.



(1) The die substrate is attached to this pad using conductive die attach material. It can not be used as a supply pin or input.

Fig.2 Pin configuration DHVQFN14.

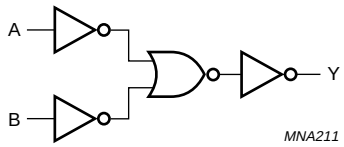


Fig.3 Logic diagram (one gate).

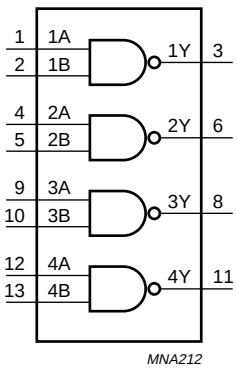


Fig.4 Function diagram.

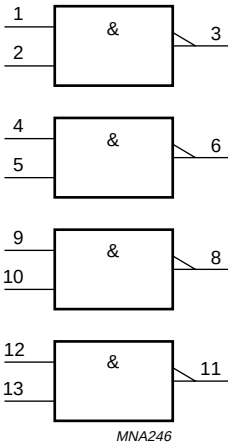


Fig.5 IEC logic symbol.